

2STR1215

Low voltage fast-switching NPN power transistor

Features

- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed
- Miniature SOT-23 plastic package for surface mounting circuits

Applications

- LED
- Battery charger
- Voltage and relay driver
- Voltage regulation

Description

The 2STR1215 is a NPN transistor manufactured using new "PB-HCD" (power bipolar high current density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage. The complementary PNP is the 2STR2215.

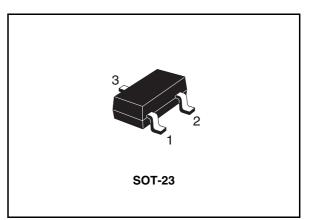


Figure 1. Internal schematic diagram

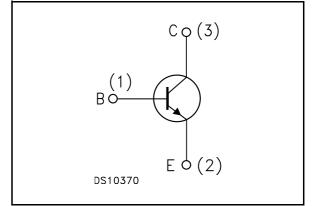


Table 1. Device summary

Order code	Marking	Package	Packaging
2STR1215	115	SOT-23	Tape and reel

1 Electrical ratings

Table 2. At	solute maximum ratings
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Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	15	V
V _{CEO}	Collector-emitter voltage $(I_B = 0)$	15	V
V _{EBO}	Emitter-base voltage (I _C = 0)	5	V
Ι _C	Collector current	1.5	А
I _{CM}	Collector peak current (t _P < 5 ms)	3	А
P _{tot}	Total dissipation at T _{amb} = 25 °C	0.5	W
T _{stg}	Storage temperature	-65 to 150	°C
Т _Ј	Max. operating junction temperature	150	°C

Table 3.Thermal data

Symbol	Parameter	Value	Unit
$R_{thj-amb}^{(1)}$	Thermal resistance junction-amb max	250	°C/W

1. Device mounted on PCB area of 1 cm^2



2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 4.	Electrical characteristics	

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E =0)	V _{CB} = 15 V			0.1	μA
I _{EBO}	Emitter cut-off current (I _C =0)	V _{EB} = 4 V			0.1	μA
V _{(BR)CBO}	Collector-base breakdown voltage (I _E = 0)	I _C = 100 μA	15			V
V _{(BR)CEO} ⁽¹⁾	Collector-emitter breakdown voltage (I _B = 0)	I _C = 10 mA	15			V
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C = 0)	I _E = 100 μA	5			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$\begin{array}{ll} I_{\rm C} = 0.1 \mbox{ A} & I_{\rm B} = 1 \mbox{mA} \\ I_{\rm C} = 1 \mbox{ A} & I_{\rm B} = 100 \mbox{ mA} \\ I_{\rm C} = 2 \mbox{ A} & I_{\rm B} = 200 \mbox{ mA} \end{array}$		0.25 0.4	0.15 0.5 0.85	V V V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	$I_{\rm C} = 1 \text{ A}$ $I_{\rm B} = 100 \text{ mA}$		0.9	1.25	V
h _{FE} ⁽¹⁾	DC current gain		200 200 130 80	280	560	
C _{CBO}	Collector-base capacitance (I _E = 0)	V _{CB} = 10 V f = 1 MHz		16		pF
t _{on} t _{off}	Resistive load Turn-on time Turn-off time	$I_{C} = 1.5 \text{ A}$ $V_{CC} = 10 \text{ V}$ $I_{B1} = -I_{B2} = 150 \text{ mA}$		60 310		ns ns

1. Pulsed duration = 300 μ s, duty cycle \leq 1.5%



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2.1 Electrical characteristics (curves)

Figure 2. DC current gain

Figure 3. Collector-emitter saturation voltage

|||||T_J=25 °C

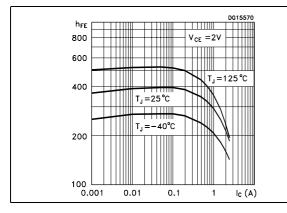
T_J =125 °C

 $T_{J} = -40$

 $h_{FE} = 100$

V_{CE (sat)} (V)

0.1





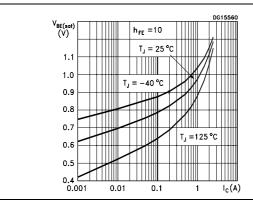
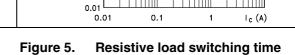
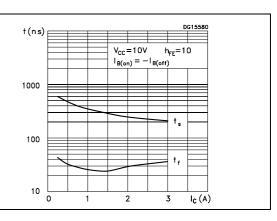
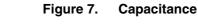


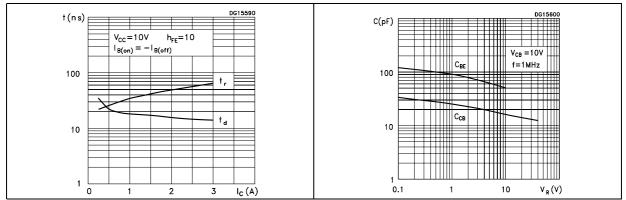
Figure 6. Resistive load switching time

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2.2 Test circuits

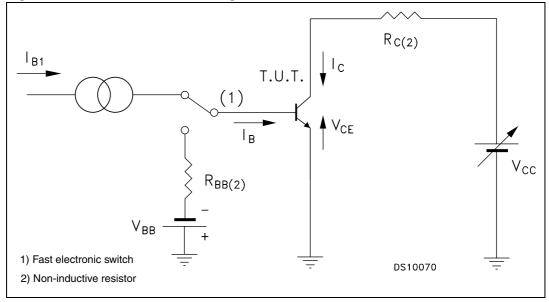


Figure 8. Resistive load switching test circuit

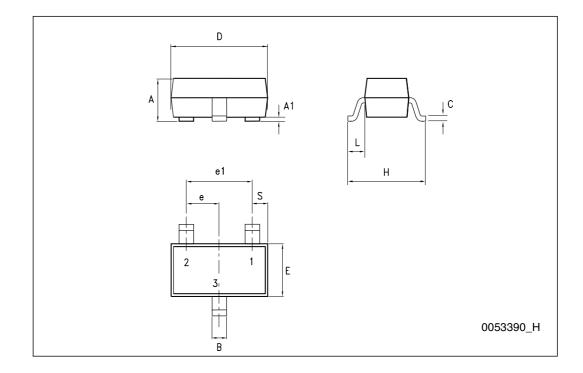


3 Package mechanical data

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SOT-23 mechanical data					
DIM.	mm.				
DIW.	min.	typ	max.		
A	0.89		1.4		
A1	0		0.1		
В	0.3		0.51		
С	0.085		0.18		
D	2.75		3.04		
е	0.85		1.05		
e1	1.7		2.1		
E	1.2		1.6		
н	2.1		2.75		
L		0.6			
S	0.35		0.65		





4 Revision history

Table 5.Document revision history

Date	Revision	Changes
09-Feb-2006	1	Initial release
18-Jul-2006	2	New template
08-Sep-2008	3	Updated the SOT-23 mechanical data
08-Jan-2009	4	Updated <i>Figure 1: Internal schematic diagram</i> Updated statement ECOPACK [®]



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